NSN 5961-01-252-0267

Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-252-0267 **Inclosure Material:** Metal **Overall Length:** 0.970 inches **Terminal Length:** 0.300 inches **Overall Height:** 0.395 inches **Overall Width:** 0.250 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Response Time:** 10.0 microseconds **Mounting Method:** Terminal and unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 collector to emitter voltage, dc **Current Rating Per Characteristic:** 30.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 75.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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